Research Article

On the Phononic Bandgap of Carbon Nanotubes

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On the phononic bandgap of carbon nanotubes (CNTs), we show in what chirality CNTs have phononic bandgaps and its dependence on the diameters of CNTs. We find that, though the rule where CNTs have phononic bandgaps is the same as in the electronic structure case, the diameter dependence is different. The phononic bandgaps of the zigzag-CNTs reveal “three” kinds of diameter dependence due to the anisotropy of graphene phonon band around the K point in k-space. We also show the crossover from one- to two-dimensional characteristics in phononic bandgaps.

Recently phononic bandgaps attract much attention. Following an analogy of the photonic crystals, in the last decade, artificial crystals with specific structures have been studied systematically to construct the phononic bandgaps since periodic structures might exhibit bandgaps in the band structures for the wave propagation [1]. Since phonon waves cannot propagate in the phononic bandgaps, the materials with effective phononic bandgaps become candidates for the applications of phonon frequency filter (Figure 1(a)), phonon beam splitter, phonon waveguide [2], and sound or vibration protection devices and thermopower waves [3]. Also phononic bandgaps play important roles in view of the reduction of thermal phonon transport, which leads to the effective heat managements [4]. Thus the control and management of phononic bandgaps are very important for various applications and have been widely studied [5].

In this respect, Sigmund and Jensen [6] studied systematic design of phononic bandgaps with topology optimization and Gazonas et al. [7] studied the optimization of phononic bandgap structures using the genetic algorithm. They dealt with sonic or ultrasonic crystals which have midgap frequencies $\omega_g = 10^2$–$10^6$ Hz. Gorishnyy et al. [8] fabricated hypersonic phononic crystals with lithography technique, and Cheng et al. [9] constructed and tuned hypersonic bandgaps in colloidal crystals which have $\omega_g = 10^9$–$10^{12}$ Hz. These phonon bandgap engineering deals with the artificially made phononic crystals. To obtain phononic bandgaps on the higher frequency requires higher skills and techniques for the fabrication, and thus materials which can be easily synthesized and to exhibit selectable hypersonic phononic bandgaps are desired. In this paper, we show that carbon nanotubes (CNTs) [10], which are easily synthesizable, have highest phononic bandgaps with $\omega_g \sim 10^{13}$ Hz. Furthermore the magnitude of phononic bandgaps of CNTs changes from 0 THz to 2 THz according to the diameters.

So far, the electronic structures of CNTs have been studied and shown to exhibit fascinating properties such as extremely high electric conductivity. The band structures of CNTs show appearance and disappearance of bandgaps at the Fermi level depending on the diameter and chirality. Correspondingly, transport properties of CNTs change from metallic to semiconducting ones according to the magnitude of bandgaps [11, 12]. The emergence of bandgaps in the electronic structures can be explained in view of the electronic states of two-dimensional (2D) graphene. While bandgaps in the electronic states of CNTs are well known, those of the phononic band structures are not clearly understood. Here, we focus on the phononic bandgap problem of CNTs.

The phononic band structures of CNTs and graphene are calculated with use of the Brenner interatomic potential [13].
The coordinates of carbon atoms of CNTs are constructed by the rolling of graphene sheet, for which the interatomic distances are optimized by the total energy minimization in the Brenner potential. The force constants are constructed in the optimization process by finite difference of the interatomic forces, which are calculated from differentiation of the total energy. The phonon dispersion relations of the system are obtained by the diagonalization of the dynamical matrix, which is constructed from the force constants [14].

Figure 1(b) shows the phonon bands of (5, 5) and (8, 0) CNTs. We see that there are no phononic bandgaps in the phonon band structure of (5, 5) CNT, while (8, 0) CNT has a phononic bandgap around 36 THz, corresponding to 150 meV. Here \( a_1 \) and \( a_2 \) are unit cell lengths for (5, 5) CNT and (8, 0) CNT, respectively.

The same method is applied to the case of phononic bandgaps with the diameters of CNTs. Figure 2(a) shows the phonon band of graphene. We see that there are only two modes around 150 meV, and these two modes are crossed at the K point in \( k \)-space. These two correspond to the longitudinal acoustic (LA) mode and the longitudinal optical (LO) mode, and no other phonon bands are present. We note that this situation is very close to the electronic band structure of graphene around the Fermi level, where two kinds of linear-dispersion bands, bonding and anti-bonding \( \pi \) bands, are crossed at the K point. This shows that the K point is a special point also in the phonon band as in the electronic band. This evidence leads us to the conclusion that, as in the electronic bands of CNTs, whether the phonon bands have finite phononic bandgaps or not is determined by the conditions that the phonon bands of graphene crosses the K point or not by the rolling up to construct the CNTs. In the electronic band structures, the zone-folding method [15] reveals that bandgaps of CNTs are made from the band of graphene at wave vectors selected by the periodic boundary condition along the circumference direction on CNTs.

The method is applied to the case of phononic bandgaps. CNTs with the index \( n - m \) equal to the multiple of 3 have no phononic bandgaps. Thus the armchair CNTs with (\( n, n \)) chirality have no phononic bandgap, because the wave vector of phonon bands of the armchair CNTs always cross the K point of phonon bands of graphene. This is observed in Figure 1 (left), which shows the phonon band of (5, 5) armchair CNT. On the other hand, the phonon bands of...
As the diameter of CNT becomes large, the effects become less important and the phononic bandgaps of CNTs with large diameter is explained in terms of the phonon band structure of graphene. In this respect, the deviation of two methods reveals the crossover from one-dimensional to two-dimensional characteristics. Let us see two special diameters for this crossover. First, we consider the optimized interatomic distance. For CNTs with small diameters, the distances between carbon atoms become longer than that of graphene. We find that, for \( n > 16 \) with the diameter of 1.3 nm, the distance of carbon atoms in CNTs agree with that of graphene, showing the crossover from tube like to sheet like. Second, a more minor point, CNTs have specific phonon dispersion relations close to the \( \Gamma \) point where acoustic phonon branches have special properties with zero frequencies. For one-dimensional material, it is known that phonon bands have four acoustic phonon branches, while only three acoustic phonon branches exist for two- and three-dimensional materials. We find that CNTs with \( n > 35 \) have only three acoustic phonons. This leads to the small deviation of phononic bandgaps of CNTs with diameters larger than about 3 nm in the zone-folding method as is seen in Figure 3. These show that, for CNTs which have diameter smaller than 1.3 nm, phonon bandgaps must be calculated directly from the phonon bands of CNTs.

To summarize, we study the phononic bandgap of CNTs. We find that the condition of chirality of CNTs which have finite phononic bandgaps is almost the same as that of the electronic bandgap case. This is due to the fact that phonon band of graphene has only two bands close to the K point at specific energy around 150 meV, while electronic band structure of graphene has only two bands around the K point at the Fermi level. Diameter dependence of phononic bandgaps is, however, quite different. We find that phononic bandgap has “three” kinds of diameter dependence, different from the electronic bandgap which has only two kinds. This difference is caused by the anisotropy of the Dirac’s cone around the K point of graphene. While the Dirac’s cone is isotropic close to the K point for phonon bands of graphene, it becomes distorted away from the K point. This changes the dependences of phononic bandgaps from three kinds for small diameter to two kinds for large diameter. Due to the curvature of CNTs at small diameter, phononic bandgaps differ with two calculating methods: direct calculation for

![Diameter dependence of phononic bandgaps of zigzag-CNTs with chirality \((n,0)\) from \( n = 6 \) to 77. Dots show phononic bandgaps from the phonon bands, and crosspoints show those by the zone-folding method. Blue colors are phononic bandgaps where \( n \) is the multiple of 3, red colors are those where \( n \) is the sum of multiples of 3 and 1, and black colors are those where \( n \) is the sum of multiple of 3 and 2.](image_url)
CNTs and zone-folding method for graphene, for which we need the direct one. As the diameter becomes large, curvature effects become less important and the difference becomes small. We find that we need the direct phonon dispersion calculation for diameter smaller than 1.3 nm and that the zone-folding method becomes reliable for diameter larger than 3 nm. This is regarded as the dimensional crossover from one- to two-dimensional characteristics in phononic bandgaps.

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